



DMP45H4D9HK3

Product Summary

BV _{DSS}	RDS(ON) Max	I _D Tc = +25°С
-450V	4.9Ω @ V _{GS} = -10V	-4.7A

Description and Applications

This MOSFET is designed to minimize the on-state resistance yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Motor Control
- DC-DC Converters
- Power Management Functions
- Uninterrupted Power Supply

450V P-CHANNEL ENHANCEMENT MODE MOSFET

Features

- Low Input Capacitance
- High BV_{DSS} Rating for Power Application
- Low Input/Output Leakage
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

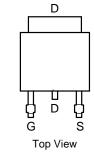
Mechanical Data

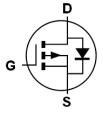
- Package: TO252
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.33 grams (Approximate)



TO252 (DPAK)

Top View





Internal Schematic

Ordering Information (Note 4)

Part Number	Paakaga	Packing		
Fait Nulliber	Package	Qty.	Carrier	
DMP45H4D9HK3-13	TO252 (DPAK)	2,500	Tape & Reel	

EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:



 $\begin{array}{l} \bigcirc 1 \\ \Rightarrow 1 \\ \Rightarrow 1 \\ \Rightarrow 2 \\$



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	VDSS	-450	V	
Gate-Source Voltage	V _{GSS}	±30	V	
Continuous Drain Current (Note 5) $V_{GS} = -10V$	lo	-4.7 -3.0	A	
Maximum Body Diode Forward Current (Note 5)		ls	-1.5	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%		ldм	-12	A
Avalanche Current, L = 60mH (Note 7)	las	-2.5	A	
Avalanche Energy, L = 60mH (Note 7)		Eas	187	mJ

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Total Power Dissipation (Note 5)	Tc = +25°C	D	104	W	
Total Power Dissipation (Note 5)	Tc = +100°C	PD	41		
Thermal Resistance, Junction to Ambient (Note 6)	R _{0JA}	41	°C/W		
Thermal Resistance, Junction to Case (Note 5)	R _{0JC}	1.2	0.700		
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C		

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)				•			
Drain-Source Breakdown Voltage	BV _{DSS}	-450	_	_	V	$V_{GS} = 0V, I_D = -250 \mu A$	
Zero Gate Voltage Drain Current	IDSS			-1	μA	$V_{DS} = -450V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}		_	±100	nA	$V_{GS} = \pm 30V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	VGS(TH)	-3.0	-4.0	-5.0	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	
Static Drain-Source On-Resistance	RDS(ON)		3.1	4.9	Ω	VGS = -10V, ID = -1.05A	
Diode Forward Voltage	Vsd		_	-1.4	V	$V_{GS} = 0V, I_{S} = -2.1A$	
Forward Transconductance	gfs	_	1.4	_	S	$V_{DS} = -50.0V, I_{D} = -1.05A$	
DYNAMIC CHARACTERISTICS (Note 7)							
Input Capacitance	Ciss	_	564	—		$V_{DS} = -25V, V_{GS} = 0V, f = 1.0MHz$	
Output Capacitance	Coss		70	_	pF		
Reverse Transfer Capacitance	Crss		3.3	_			
Total Gate Charge (V _{GS} = -10V)	Qg		13.7	_			
Gate-Source Charge	Qgs		3.4	_	nC	V _{DS} = -360V, I _D = -2.7A, V _{GS} = -10V	
Gate-Drain Charge	Q _{gd}	_	6.0	_			
Turn-On Delay Time	td(on)	_	21	_			
Turn-On Rise Time	tR	_	54	_		$V_{DD} = -225V, R_G = 3.0\Omega, I_D = -2.7A$	
Turn-Off Delay Time	t _{D(OFF)}	_	34	—	ns		
Turn-Off Fall Time	t⊨		34				
Body Diode Reverse Recovery Time	t _{RR}	_	168	_	ns	VGS = 0V, VDD = -200V, IS = -2.7A,	
Body Diode Reverse Recovery Charge	Q _{RR}	_	1.3		μC	dl/dt = 100A/µs	

Notes:

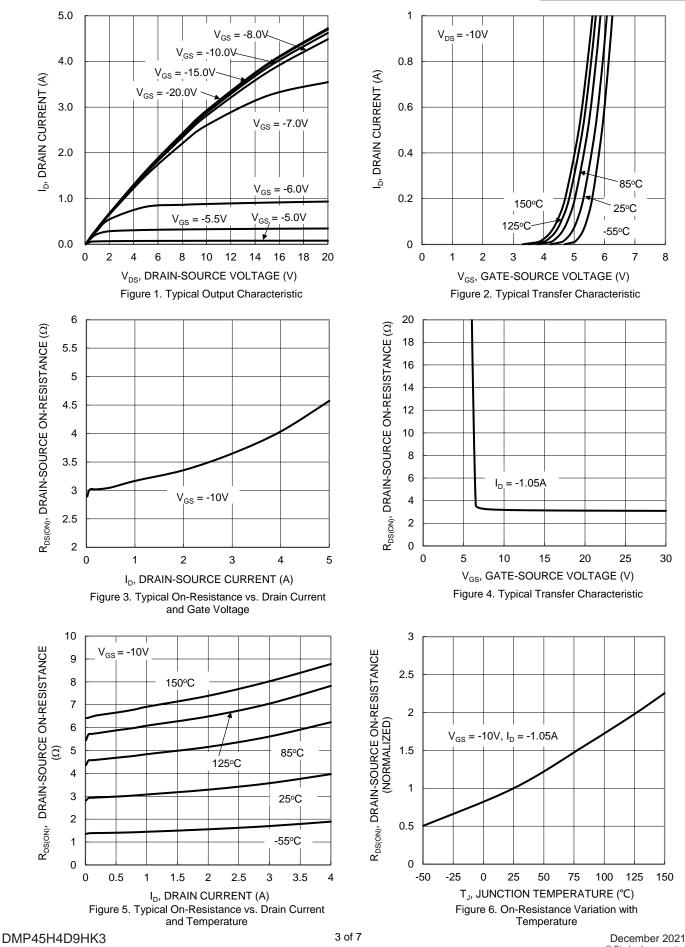
Device mounted on infinite heatsink.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper pad layout.

7. Guaranteed by design. Not subject to production testing.

8. Short duration pulse test used to minimize self-heating effect.



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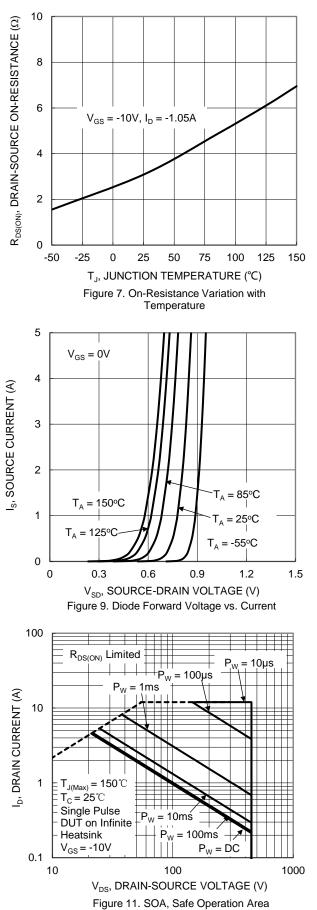
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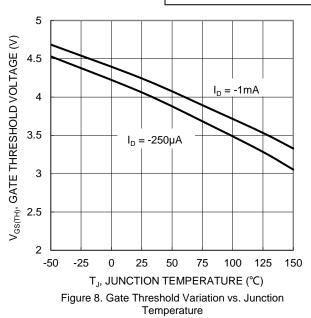
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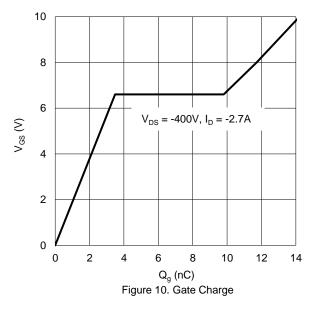
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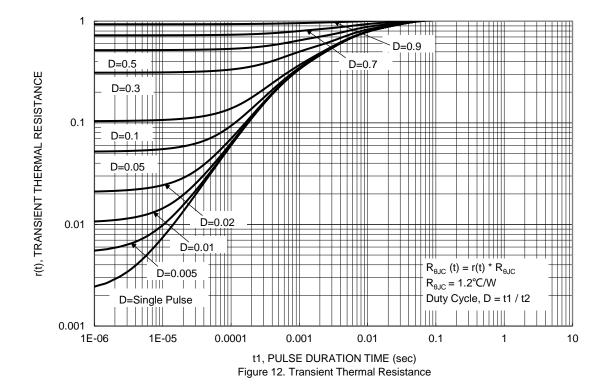
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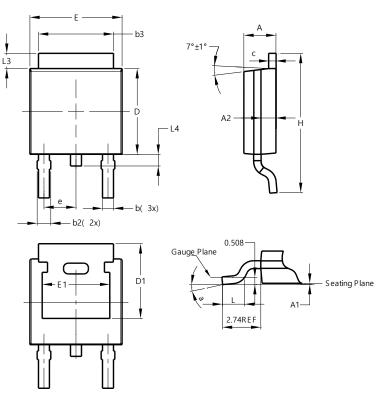






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

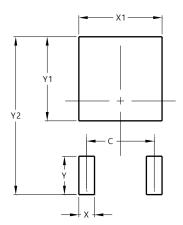


TO252 (DPAK)						
Dim	Min	· ·	<i>'</i>			
		Max	Тур			
Α	2.19	2.39	2.29			
A1	0.00	0.13	0.08			
A2	0.97	1.17	1.07			
b	0.64	0.88	0.783			
b2	0.76	1.14	0.95			
b3	5.21	5.46	5.33			
С	0.45	0.58	0.531			
D	6.00	6.20	6.10			
D1	5.21	-	-			
е	-	-	2.286			
E	6.45	6.70	6.58			
E1	4.32	-	-			
Η	9.40	10.41	9.91			
L	1.40	1.78	1.59			
L3	0.88	1.27	1.08			
L4	0.64	1.02	0.83			
а	0°	10°	-			
All	All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

TO252 (DPAK)



Dimensions	Value (in mm)
С	4.572
Х	1.060
X1	5.632
Y	2.600
Y1	5.700
Y2	10.700



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